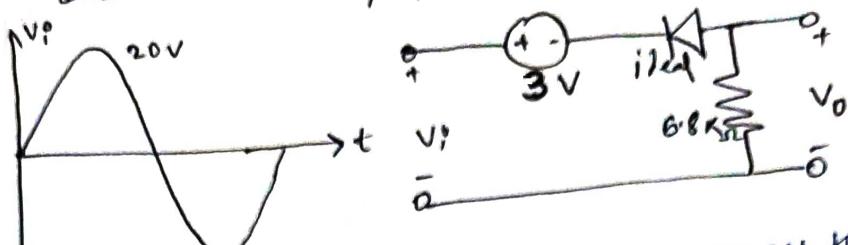


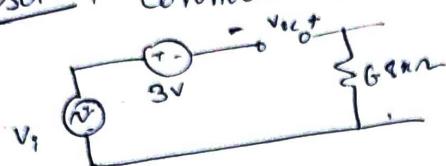
Solution of EE101 Tutorial 3

Q1.

Determine V_o , for the input shown



Solⁿ: Consider the open circuit voltage across the diode
 $V_{oc} = 3V - V_I$; ($V_{oc} = V_T - V_D$)

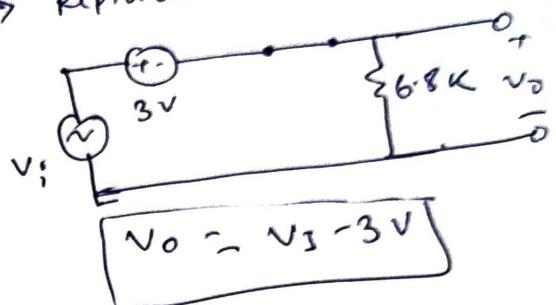


Case-1: Diode is ON, \rightarrow Replace the Diode by short circuit

$$V_{oc} > 0V$$

$$\Rightarrow 3 - V_I > 0$$

$$\Rightarrow V_I < 3V$$

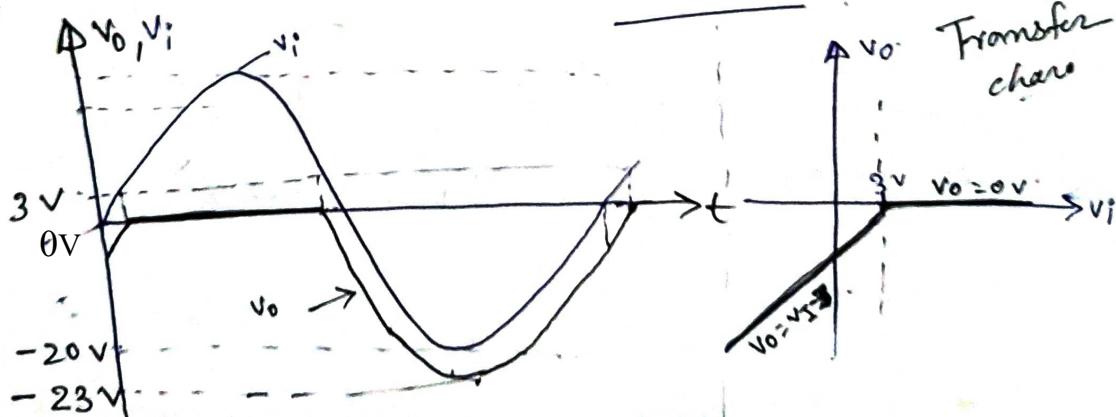
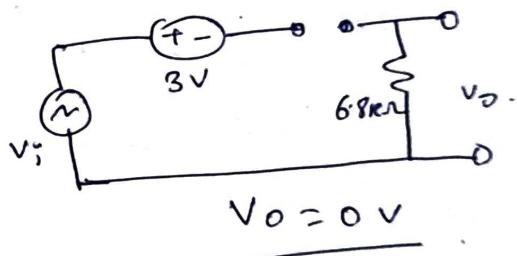


Case-2: Diode-off \rightarrow Replace the diode by open circuit

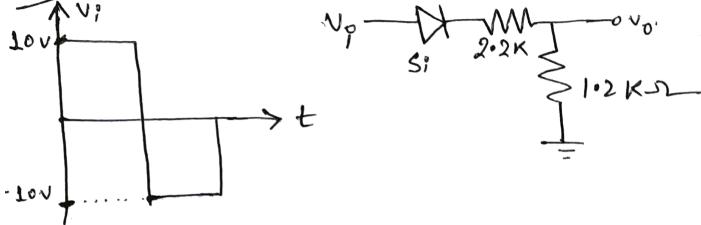
$$V_{oc} < 0V$$

$$\Rightarrow 3 - V_I < 0V$$

$$\Rightarrow V_I > 3V$$



Q.No.2° Determine V_o for the input shown.



$$\underline{\underline{\text{Soln}}} : \quad V_{oc} = V_o - 0$$

Case-1: Diode is ON \rightarrow Replace the diode with V_g source of V_{ON}

$$V_{oc} > V_{ON} \quad \Rightarrow \quad V_i > 0.7V$$

Circuit diagram for Case-1:

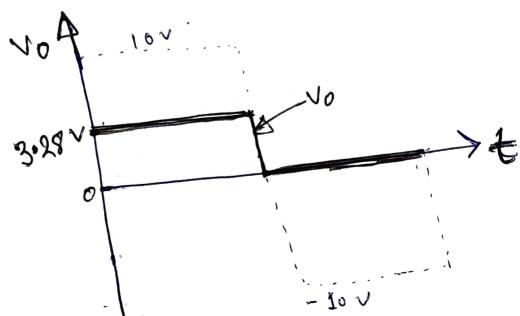
$$V_o = \frac{1.2k\Omega}{1.2 + 2.2} (9.3V) \Rightarrow V_o = 3.28V$$

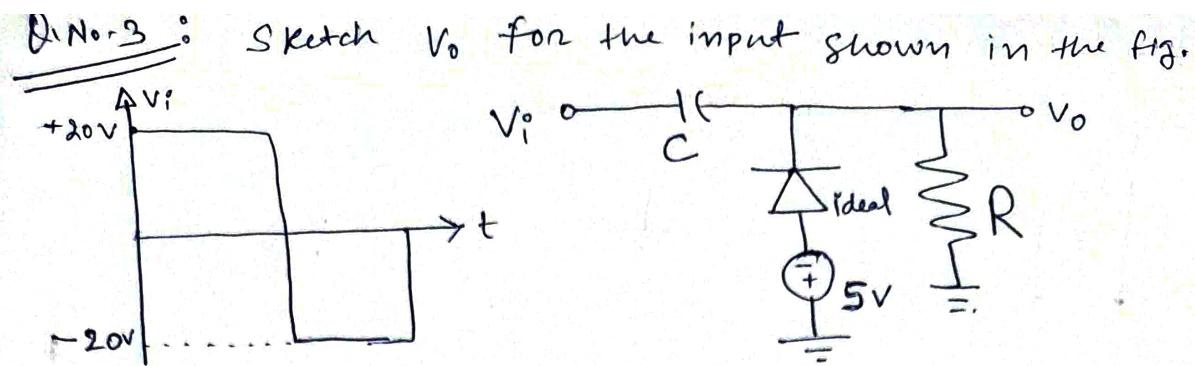
Case-2: Diode-off \rightarrow Replace the diode with open circuit

$$V_{oc} < V_{ON} \quad \Rightarrow \quad V_i < 0.7V$$

Circuit diagram for Case-2:

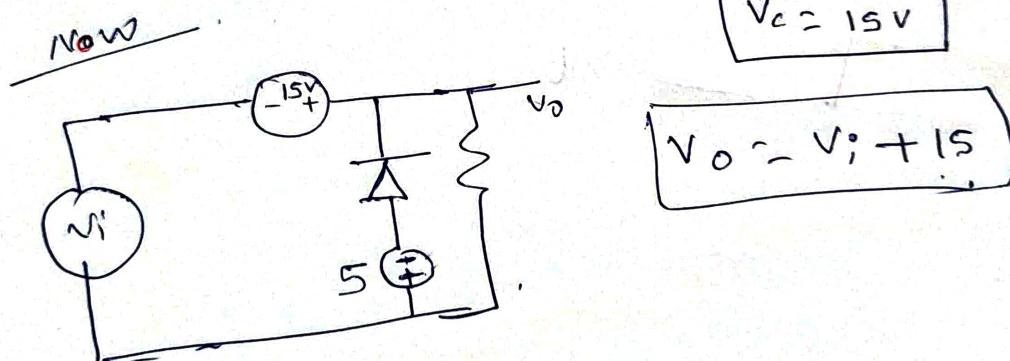
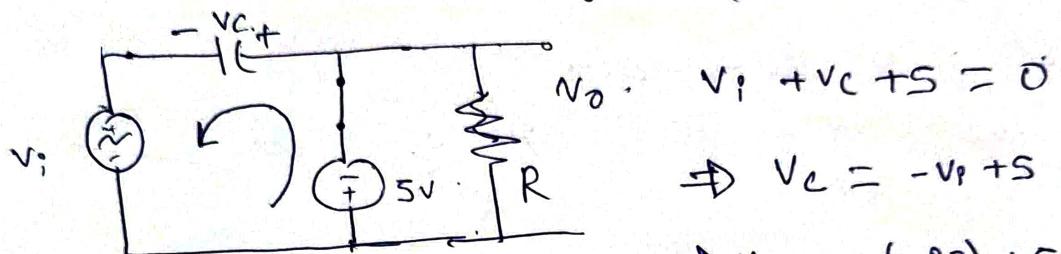
$$V_o = 0V$$



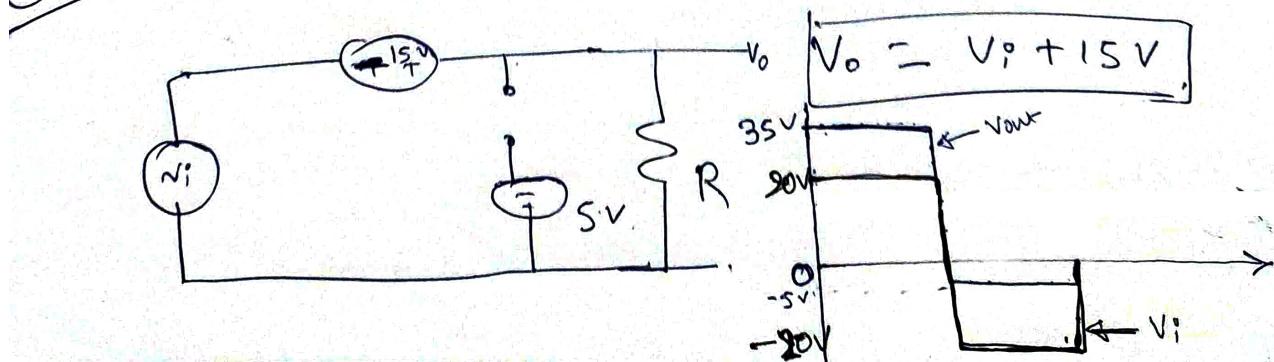


SOL 1M : [Note:- start the Analysis of clamping networks by considering the part of input that will forward bias the diode]

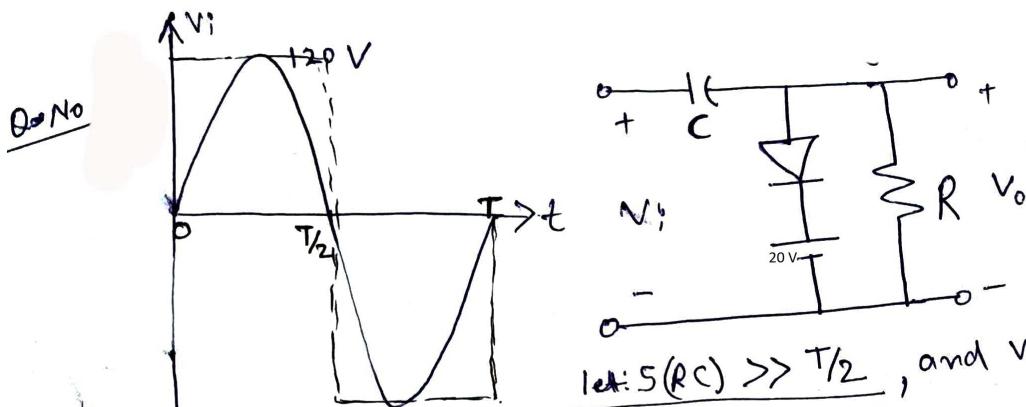
Case-3 : during the -ve half cycle, (diode-on).



Case 2 : during the +ve cycle (diode-off)



Q4.



$$\text{Let } 5(RC) \gg T/2, \text{ and } V_{ON} = 0V,$$

SOL^W: Replace the given input sinusoidal waveform with square waveform between the same two levels.

for $0 < t < T/2$

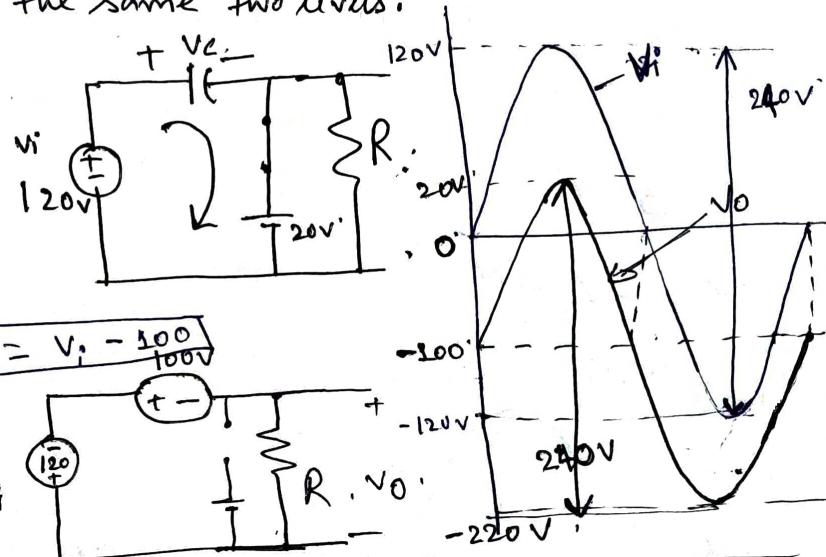
Applying KVL

$$120 - V_c - 20 = 0$$

$$\Rightarrow V_c = 100V$$

$$\text{for } T/2 < t < T \Rightarrow V_o = V_i - \frac{100}{1000}$$

$$V_i - 100 - V_o = 0 \quad V_i$$



$$V_o = V_i - 100V$$

even if we consider $V_o = 0.7V$, the peak voltages are much higher than V_{ON} , so effective swing will not change by significant amount

Q5. A.

$$I_x = 1^{\text{mA}} \Rightarrow I_{Q_1} = I_{Q_2} = 0.5^{\text{mA}}$$

$$I_{Q_1} = I_S e^{\frac{V_{BE1}}{V_T}} \Rightarrow 5 \times 10^{-4} = 3 \times 10^{-16} e^{\frac{V_B}{26^{\text{mV}}}}$$

$$\Rightarrow V_B = 26^{\text{mV}} \ln\left(\frac{5}{3} \times 10^{12}\right) \Rightarrow V_B \approx 731.7^{\text{mV}}$$

B.

$$I_Y = I_{S_3} e^{\frac{V_B}{V_T}}$$

$$\Rightarrow I_{S_3} = I_Y e^{-\frac{V_B}{V_T}} = 2.5 \times 10^{-3} \times e^{-\frac{V_B}{26 \text{ mV}}} = 2.5 \times 10^{-3} \times \frac{1}{5.3 \times 10^{12}}$$

$$\Rightarrow \boxed{I_{S_3} = 1.5 \times 10^{-15} \text{ A}}$$

Q6. A.

$$I_X = I_1 + I_2$$

$$I_X = I_{S_1} e^{\frac{V_B}{V_T}} + I_{S_2} e^{\frac{V_B}{V_T}} \Rightarrow I_X = (I_{S_1} + I_{S_2}) e^{\frac{V_B}{V_T}}$$

$$V_B = V_T \ln \left(\frac{I_X}{I_{S_1} + I_{S_2}} \right) \xrightarrow{I_{S_1} = 2I_{S_2}} \boxed{V_B = V_T \ln \left(\frac{I_X}{\frac{3}{2} I_{S_1}} \right)}$$

$$V_B = 26 \times 10^{-3} \ln \left(\frac{1.2 \times 10^{-3}}{\frac{3}{2} \times 5 \times 10^{-16}} \right) \Rightarrow \boxed{V_B \approx 730.6 \text{ mV}}$$

B.

Transistors at the edge of the active mode $\Rightarrow V_C = V_B$

applying KVL, we have:

$$V_{CC} = R_C I_X + V_B \Rightarrow \boxed{R_C = \frac{V_{CC} - V_B}{I_X}}$$

$$\Rightarrow R_C = \frac{2.5 - 0.73}{1.2 \times 10^{-3}}$$

$$\Rightarrow \boxed{R_C \approx 1475 \Omega}$$

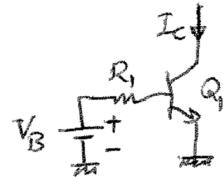
Q7.

$$\begin{aligned}
 V_{BE} &= 1.5 \text{ V} - I_E(1 \text{ k}\Omega) \\
 &\approx 1.5 \text{ V} - I_C(1 \text{ k}\Omega) \text{ (assuming } \beta \gg 1) \\
 &= V_T \ln \left(\frac{I_C}{I_S} \right) \\
 I_C &= 775 \mu\text{A} \\
 V_X &\approx I_C(1 \text{ k}\Omega) \\
 &= \boxed{775 \text{ mV}}
 \end{aligned}$$

Q8.

From KVL,

$$V_B = R_1 I_B + V_{BE_{Q_1}}$$



$$I_B = \frac{I_C}{\beta} = \frac{1 \text{ mA}}{100} \Rightarrow \boxed{I_B = 10^{-5} \text{ A}}$$

$$V_{BE_{Q_1}} = V_T \ln \left(\frac{I_C}{I_S} \right) = 26 \times 10^{-3} \ln \left(\frac{10^{-3}}{7 \times 10^{-16}} \right)$$

$$\Rightarrow \boxed{V_{BE_{Q_1}} \simeq 727.7 \text{ mV}}$$

Therefore,

$$\begin{aligned}
 V_B &= R_1 I_B + V_{BE_{Q_1}} \\
 &\simeq 10 \times 10^{-5} \text{ A} + 728 \times 10^{-3} \\
 \Rightarrow V_B &\simeq 0.1 + 0.728 \Rightarrow \boxed{V_B \simeq 0.828 \text{ V}}
 \end{aligned}$$

Q9.

First, note that $V_{BE1} = V_{BE2} = V_{BE}$.

$$\begin{aligned}
 V_B &= (I_{B1} + I_{B2})R_1 + V_{BE} \\
 &= \frac{R_1}{\beta}(I_X + I_Y) + V_T \ln(I_X/I_{S1}) \\
 I_{S2} &= \frac{5}{3}I_{S1} \\
 \Rightarrow I_Y &= \frac{5}{3}I_X \\
 V_B &= \frac{8R_1}{3\beta}I_X + V_T \ln(I_X/I_{S1}) \\
 I_X &= \boxed{509 \mu A} \\
 I_Y &= \boxed{848 \mu A}
 \end{aligned}$$

Q10.

$$\begin{aligned}
 g_m &= \frac{I_C}{V_T} \\
 \Delta g_m &= \frac{\Delta I_C}{V_T} = \frac{1}{V_T} \Delta (I_S e^{\frac{V_{BE}}{V_T}}) \approx \frac{I_S}{V_T^2} e^{\frac{V_{BE}}{V_T}} \Delta V_{BE} \\
 \Rightarrow \boxed{\Delta g_m \approx \frac{I_C}{V_T^2} \Delta V_{BE}} \\
 \Rightarrow \Delta g_m &\approx \frac{g_m}{V_T} \Delta V_{BE} \\
 \Rightarrow \boxed{\frac{\Delta g_m}{g_m} \approx \frac{1}{V_T} \Delta V_{BE}} \\
 \frac{\Delta g_m}{g_m} \Bigg|_{I_C=1mA}^{\max} 0.1 &\Rightarrow \Delta V_{BE}^{\max} = 0.1 V_T \\
 &\Rightarrow \boxed{\Delta V_{BE} \leq 2.6 mV}
 \end{aligned}$$

Q11.

$$V_{BE} = V_{CC} - I_B R_B$$

$$V_T \ln(I_C/I_S) = V_{CC} - I_C R_B / \beta$$

$$I_C = 1.67 \text{ mA}$$

$$V_{BC} = V_{CC} - I_B R_B - (V_{CC} - I_C R_C)$$

$$< 200 \text{ mV}$$

$$I_C R_C - I_B R_B < 200 \text{ mV}$$

$$R_C < \frac{200 \text{ mV} + I_B R_B}{I_C}$$

$$= \frac{200 \text{ mV} + I_C R_B / \beta}{I_C}$$

$$R_C < \boxed{1.12 \text{ k}\Omega}$$